

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

GERT BURBACH FRANK HEINLEIN JOHANNES GROSCHOPF GOTTHARD JUNGNICKEL HARTMUT RUELKE CARSTEN HARTIG

Serial No.: Unknown

Filed: May 3, 2001

For: METHOD OF FORMING A SUBSTRATE

CONTACT IN A FIELD EFFECT TRANSISTOR FORMED OVER A BURIED INSULATOR LAYER Group Art Unit: Unknown

Examiner: Unknown

Att'y Docket: 2000.064400/DE0058

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Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Transmitted for filing herewith is the certified copy of the priority document – German Patent Application No. 100 54 109.7 filed on October 31, 2000.

If any fees under 37 C.F.R. §§ 1.16 to 1.21 be required for any reason relating to the enclosed materials, the Assistant Commissioner is authorized to said fees Advanced Micro Devices, Inc. Deposit Account No. 01-0365/DE0058.

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Date: May 3, 2001

Respectfully submitted,

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Prioritätsbescheinigung über die Einreichung einer Patentanmeldung

Aktenzeichen:

100 54 109.7

Anmeldetag:

31. Oktober 2000

Anmelder/Inhaber:

ADVANCED MICRO DEVICES, INC., Sunnyva-

le, Calif./US

Bezeichnung:

A METHOD OF FORMING A SUBSTRATE CONTACT IN A FIELD EFFECT TRANSISTOR

FORMED OVER A BURIED INSULATOR

LAYER

IPC:

H 01 L 21/336

Die angehefteten Stücke sind eine richtige und genaue Wiedergabe der ursprünglichen Unterlagen dieser Patentanmeldung.

München, den 1. März 2001 Deutsches Patent- und Markenamt

Der Präsident

Irh Auftrag

